

Section I. (Amendment to the Claims)

Please amend claims 1, 3-8, 18-22, 26-28, 31, 37, 38, 44, 49, 51-56, 66-70, 74-76, 78, 79, 85, 86 and 92, cancel claims 2, 15-17, 30, 41, 50, 63-65, and 89, and add claim 97, as set out below in the listing of claims 1-97 of the application.

1. (Currently Amended) A composition for cleaning semiconductor wafers, wherein the composition includes supercritical fluid, ~~and at least one additive selected from the group consisting of:~~

- (I) fluoro species~~[[;]]~~, and an inhibitor that is effective to inhibit attack of the cleaning composition on low dielectric constant layer material, wherein said inhibitor comprises boric acid
- (II) ~~primary and/or secondary amine(s).~~

2. (Cancelled)

3. (Currently Amended) The composition of claim 1 ~~[[2]]~~, wherein the supercritical fluid comprises a supercritical fluid species selected from the group consisting of carbon dioxide, oxygen, argon, krypton, xenon, ammonia, methane, methanol, dimethyl ketone, hydrogen, forming gas, and sulfur hexafluoride.

4. (Currently Amended) The composition of claim 1 ~~[[2]]~~, wherein the supercritical fluid comprises carbon dioxide.

5. (Currently Amended) The composition of claim 1 ~~[[2]]~~, wherein the fluoro species comprises a fluorine-containing material selected from the group consisting of hydrogen fluoride (HF), ammonium fluoride (NH₄F), alkyl hydrogen fluoride (NRH₃F), dialkylammonium hydrogen fluoride (NR₂H₂F), trialkylammonium hydrogen fluoride (NR₃HF), trialkylammonium trihydrogen fluoride (NR₃(3HF)), tetraalkylammonium fluoride (NR₄F), and xenon difluoride (XeF₂), wherein each R is independently selected from C₁-C₈ alkyl and C₆-C₁₀ aryl.

6. (Currently Amended) The composition of claim 1 ~~[[2]]~~, wherein the fluoro species comprises triethylamine trihydrogen fluoride.

7. (Currently Amended) The composition of claim 1 [[2]], wherein the fluoro species comprises ammonium fluoride.
8. (Currently Amended) The composition of claim 1 [[2]], further comprising co-solvent.
9. (Original) The composition of claim 8, wherein the co-solvent comprises at least one solvent species selected from the group consisting of alcohols, amides, ketones, and esters.
10. (Original) The composition of claim 8, wherein the co-solvent comprises at least one solvent species selected from the group consisting of alcohols, N-alkylpyrrolidones, N-arylpyrrolidones, dimethylsulfoxide, sulfolane, catechol, ethyl lactate, acetone, butyl carbitol, monoethanolamine, butyrol lactone, diglycol amine, γ -butyrolactone, butylene carbonate, ethylene carbonate, and propylene carbonate, wherein alkyl is C₁-C₈ alkyl and aryl is C₆-C₁₀ aryl.
11. (Original) The composition of claim 8, wherein the co-solvent comprises at least one alcohol.
12. (Original) The composition of claim 8, wherein the co-solvent comprises at least one solvent species selected from the group consisting of methanol, ethanol, and isopropyl alcohol.
13. (Original) The composition of claim 8, wherein the co-solvent comprises at least one solvent species selected from the group consisting of N-methyl-, N-octyl-, and N-phenyl- pyrrolidones.
14. (Original) The composition of claim 8, wherein the co-solvent comprises at least one solvent species selected from the group consisting of ethanol and isopropyl alcohol.
- 15.-17. (Cancelled)
18. (Currently Amended) The composition of claim 1 [[2]], wherein the supercritical fluid species comprises a substantial major fraction of the cleaning composition.
19. (Currently Amended) The composition of claim 1 [[2]], wherein the supercritical fluid

species is present in an amount of from about 75% by weight to about 99.01% by weight, based on the total weight of the composition.

20. (Currently Amended) The composition of claim 1 [[2]], wherein the supercritical fluid species is present in an amount of from about 80% by weight to about 99.01% by weight, based on the total weight of the composition.

21. (Currently Amended) The composition of claim 1 [[2]], wherein the fluoro species is present in an amount of from about 0.01% by weight to about 5% by weight, based on the total weight of the composition.

22. (Currently Amended) The composition of claim 1 ~~15~~, wherein the inhibitor is present in an amount of up to about 5% by weight, based on the total weight of the composition.

23. (Original) The composition of claim 8, wherein the co-solvent is present in an amount of up to about 25% by weight, based on the total weight of the composition.

24. (Original) The composition of claim 8, wherein the co-solvent is present in an amount of up to about 20% by weight, based on the total weight of the composition.

25. (Original) The composition of claim 8, wherein the co-solvent is present in an amount of from about 1% to about 20% by weight, based on the total weight of the composition.

26. (Currently Amended) The composition of claim 1 [[2]], having the following formulation, wherein all percentages are by weight:

Carbon dioxide: 80-99.01% (w/w)

Fluoride species: 0.01-5.0% (w/w)

Low-k material attack inhibitor: [[0.0-]] up to 5.0% (w/w)

Co-solvent: 0-20% (w/w)

TOTAL: 100% by weight.

27. (Currently Amended) The composition of claim 1 [[2]], having the following formulation,

wherein all percentages are by weight:

Carbon dioxide: 80-99% (w/w)

Fluoride species: 0.01-5.0% (w/w)

Co-solvent: 1-20% (w/w)

Low-k material attack inhibitor: up to 5.0% (w/w)

Surfactant: 0.0-5.0% (w/w)

TOTAL: 100% by weight.

28. (Currently Amended) A composition for cleaning semiconductor wafers, wherein the composition includes supercritical fluid, at least one ~~The composition of claim 1, comprising~~ primary and/or secondary amine(s), and at least one surfactant, wherein the primary and/or secondary amine(s) include at least one amine species selected from the group consisting of hydroxylamine (NH₂OH), ammonia (NH₃), alkylamines (R-NH₂) and dialkylamines (R₁R₂NH), wherein R, R₁ and R₂ are each independently selected from C₁-C₆ alkyl and C₆ aryl.

29. (Original) The composition of claim 28, further comprising co-solvent.

30. (Cancelled)

31. (Currently Amended) The composition of claim 28, further comprising an inhibitor that is effective to inhibit attack of the cleaning composition on low dielectric constant layer material ~~co-solvent and surfactant.~~

32. (Original) The composition of claim 28, wherein the supercritical fluid is present in an amount of from about 75% by weight to about 99.01% by weight, based on the total weight of the composition.

33. (Original) The composition of claim 28, wherein the supercritical fluid is present in an amount of from about 80% by weight to about 99% by weight, based on the total weight of the composition.

34. (Original) The composition of claim 28, comprising from about 0.01% to about 5.0% by

weight of the primary and/or secondary amine(s), based on the total weight of the composition.

35. (Original) The composition of claim 29, comprising from about 1% to about 25% by weight of co-solvent, based on the total weight of the composition.

36. (Original) The composition of claim 29, comprising from about 1% to about 20% by weight of co-solvent, based on the total weight of the composition.

37. (Currently Amended) The composition of claim ~~28~~ 30, comprising up to about 5% by weight of surfactant, based on the total weight of the composition.

38. (Currently Amended) The composition of claim 28, comprising from about 80 to about 99.01% by weight of SCCO_2 , from about 0.01% to about 5.0% by weight of primary and/or secondary amine, from about 1% to about 20% by weight of co-solvent, and ~~optionally~~ up to 5% by weight of surfactant, with all ingredient weight percentages being based on the total weight of the composition, and with all weight percentage amounts of such ingredients totaling to 100 weight %.

39. (Original) The composition of claim 28, wherein the supercritical fluid comprises a fluid species selected from the group consisting of carbon dioxide, oxygen, argon, krypton, xenon, ammonia, methane, methanol, dimethyl ketone, hydrogen, forming gas, and sulfur hexafluoride.

40. (Original) The composition of claim 28, wherein the supercritical fluid comprises carbon dioxide.

41. (Cancelled)

42. (Original) The composition of claim 29, wherein the co-solvent comprises at least one solvent species selected from the group consisting of alcohols, amides, ketones, esters, lactones, and 1,3-diones.

43. (Original) The composition of claim 29, wherein the co-solvent comprises isopropyl alcohol.

44. (Currently Amended) The composition of claim ~~28~~ 30, wherein the surfactant comprises a non-ionic surfactant.

45. (Original) The composition of claim 1, at pressure in a range of from about 800 to about 10,000 psi.

46. (Original) The composition of claim 45, at temperature in a range of from about 20 to about 150°C.

47. (Original) The composition of claim 45, at temperature in a range of from about 40 to about 100°C.

48. (Original) The composition of claim 45, at temperature in a range of from about 75 to about 80°C.

49. (Withdrawn) A method of cleaning of a semiconductor wafer, comprising contacting the semiconductor wafer with a supercritical fluid-based cleaning composition including supercritical fluid, ~~and at least one additive selected from the group consisting of:~~

(I) fluoro species[[:]], and an inhibitor that is effective to inhibit attack of the cleaning composition on low dielectric constant layer material, wherein said inhibitor comprises boric acid

(II) ~~primary and/or secondary amine(s).~~

50. (Cancelled)

51. (Withdrawn) The method of claim ~~49~~ 50, wherein the supercritical fluid comprises a supercritical fluid species selected from the group consisting of carbon dioxide, oxygen, argon, krypton, xenon, ammonia, methane, methanol, dimethyl ketone, hydrogen, forming gas, and sulfur hexafluoride.

52. (Withdrawn) The method of claim ~~49~~ 50, wherein the supercritical fluid comprises carbon

dioxide.

53. (Withdrawn) The method of claim 49 50, wherein the fluoro species comprises a fluorine-containing material selected from the group consisting of hydrogen fluoride (HF), ammonium fluoride (NH_4F), alkyl hydrogen fluoride (NRH_3F), dialkylammonium hydrogen fluoride ($\text{NR}_2\text{H}_2\text{F}$), trialkylammonium hydrogen fluoride (NR_3HF), trialkylammonium trihydrogen fluoride ($\text{NR}_3(3\text{HF})$), tetraalkylammonium fluoride (NR_4F), and xenon difluoride (XeF_2), wherein each R is independently selected from C_1 - C_8 alkyl and C_6 - C_{10} aryl.

54. (Withdrawn) The method of claim 49 50, wherein the fluoro species comprises triethylamine trihydrogen fluoride.

55. (Withdrawn) The method of claim 49 50, wherein the fluoro species comprises ammonium fluoride.

56. (Withdrawn) The method of claim 49 50, wherein the composition further comprises co-solvent.

57. (Withdrawn) The method of claim 56, wherein the co-solvent comprises at least one solvent species selected from the group consisting of alcohols, amides, ketones, and esters.

58. (Withdrawn) The method of claim 56, wherein the co-solvent comprises at least one solvent species selected from the group consisting of alcohols, N-alkylpyrrolidones, N-arylpyrrolidones, dimethylsulfoxide, sulfolane, catechol, ethyl lactate, acetone, butyl carbitol, monoethanolamine, butyrol lactone, diglycol amine, γ -butyrolactone, butylene carbonate, ethylene carbonate, and propylene carbonate, wherein alkyl is C_1 - C_8 alkyl and aryl is C_6 - C_{10} aryl.

59. (Withdrawn) The method of claim 56, wherein the co-solvent comprises at least one alcohol.

60. (Withdrawn) The method of claim 56, wherein the co-solvent comprises at least one solvent species selected from the group consisting of methanol, ethanol, and isopropyl alcohol.

61. (Withdrawn) The method of claim 56, wherein the co-solvent comprises at least one solvent species selected from the group consisting of N-methyl-, N-octyl-, and N-phenyl- pyrrolidones.

62. (Withdrawn) The method of claim 56, wherein the co-solvent comprises at least one solvent species selected from the group consisting of ethanol and isopropyl alcohol.

63.-65. (Cancelled)

66. (Withdrawn) The method of claim 49 ~~50~~, wherein the supercritical fluid species comprises a substantial major fraction of the cleaning composition.

67. (Withdrawn) The method of claim 49 ~~50~~, wherein the supercritical fluid species is present in the composition in an amount of from about 75% by weight to about 99.01% by weight, based on the total weight of the composition.

68. (Withdrawn) The method of claim 49 ~~50~~, wherein the supercritical fluid species is present in an amount of from about 80% by weight to about 99.01% by weight, based on the total weight of the composition.

69. (Withdrawn) The method of claim 49 ~~50~~, wherein the fluoro species is present in an amount of from about 0.01% by weight to about 5% by weight, based on the total weight of the composition.

70. (Withdrawn) The method of claim 49 ~~63~~, wherein the inhibitor is present in an amount of up to about 5% by weight, based on the total weight of the composition.

71. (Withdrawn) The method of claim 56, wherein the co-solvent is present in an amount of up to about 25% by weight, based on the total weight of the composition.

72. (Withdrawn) The method of claim 56, wherein the co-solvent is present in an amount of up to about 20% by weight, based on the total weight of the composition.

73. (Withdrawn) The method of claim 56, wherein the co-solvent is present in an amount of from about 1% to about 20% by weight, based on the total weight of the composition.

74. (Withdrawn) The method of claim 49 50, wherein the composition has the following formulation, wherein all percentages are by weight:

Carbon dioxide: 80-99.01% (w/w)

Fluoride species: 0.01-5.0% (w/w)

Low-k material attack inhibitor: [[0.0-]] up to 5.0% (w/w)

Surfactant: up to 5.0% (w/w)

Co-solvent: 0-20% (w/w)

TOTAL: 100% by weight.

75. (Withdrawn) The method of claim 49 50, wherein the composition has the following formulation, wherein all percentages are by weight:

Carbon dioxide: 80-99% (w/w)

Fluoride species: 0.01-5.0% (w/w)

Co-solvent: 1-20% (w/w)

Surfactant: [[0.0-]] up to 5.0% (w/w)

TOTAL: 100% by weight.

76. (Withdrawn) A method of cleaning of a semiconductor wafer, comprising contacting the semiconductor wafer with a supercritical fluid-based cleaning composition including supercritical fluid, at least one ~~The method of claim 49, wherein the composition comprises~~ primary and/or secondary amine(s), and at least one surfactant, wherein the primary and/or secondary amine(s) include at least one amine species selected from the group consisting of hydroxylamine (NH₂OH), ammonia (NH₃), alkylamines (R-NH₂) and dialkylamines (R₁R₂NH), wherein R, R₁ and R₂ are each independently selected from C₁-C₆ alkyl and C₆ aryl.

77. (Withdrawn) The method of claim 76, wherein the composition further comprises co-solvent.

78. (Withdrawn) The method of claim 79 76, wherein the ~~composition further comprises~~ surfactant inhibitor comprises boric acid.

79. (Withdrawn) The method of claim 76, wherein the composition further comprises ~~co-solvent and surfactant~~ an inhibitor that is effective to inhibit attack of the cleaning composition on low dielectric constant layer material.

80. (Withdrawn) The method of claim 76, wherein the supercritical fluid is present in the composition in an amount of from about 75% by weight to about 99.01% by weight, based on the total weight of the composition.

81. (Withdrawn) The method of claim 76, wherein the supercritical fluid is present in the composition in an amount of from about 80% by weight to about 99% by weight, based on the total weight of the composition.

82. (Withdrawn) The method of claim 76, wherein the composition comprises from about 0.01% to about 5.0% by weight of the primary and/or secondary amine(s), based on the total weight of the composition.

83. (Withdrawn) The method of claim 77, wherein the composition comprises from about 1% to about 25% by weight of co-solvent, based on the total weight of the composition.

84. (Withdrawn) The method of claim 77, wherein the composition comprises from about 1% to about 20% by weight of co-solvent, based on the total weight of the composition.

85. (Withdrawn) The method of claim ~~76~~ 78, wherein the composition comprises up to about 5% by weight of surfactant, based on the total weight of the composition.

86. (Withdrawn) The method of claim 77, wherein the composition comprises from about 80 to about 99.01% by weight of SCCO_2 , from about 0.01% to about 5.0% by weight of primary and/or secondary amine, from about 1% to about 20% by weight of co-solvent, and ~~optionally~~ up to 5% by weight of surfactant, with all ingredient weight percentages being based on the total weight of the composition, and with all weight percentage amounts of such ingredients totaling to 100 weight %.

87. (Withdrawn) The method of claim 76, wherein the supercritical fluid comprises a fluid species selected from the group consisting of carbon dioxide, oxygen, argon, krypton, xenon, ammonia, methane, methanol, dimethyl ketone, hydrogen, forming gas, and sulfur hexafluoride.

88. (Withdrawn) The method of claim 76, wherein the supercritical fluid comprises carbon dioxide.

89. (Cancelled)

90. (Withdrawn) The method of claim 77, wherein the co-solvent comprises at least one solvent species selected from the group consisting of alcohols, amides, ketones, esters, lactones, and 1,3-diones.

91. (Withdrawn) The method of claim 77, wherein the co-solvent comprises isopropyl alcohol.

92. (Withdrawn) The method of claim 76 ~~78~~, wherein the surfactant comprises a non-ionic surfactant.

93. (Withdrawn) The method of claim 49, wherein the contacting step is carried out at pressure in a range of from about 800 to about 10,000 psi.

94. (Withdrawn) The method of claim 93, wherein the contacting step is carried out at temperature in a range of from about 20 to about 150°C.

95. (Withdrawn) The method of claim 93, wherein the contacting step is carried out at temperature in a range of from about 40 to about 100°C.

96. (Withdrawn) The method of claim 93, wherein the contacting step is carried out at temperature in a range of from about 75 to about 80°C.

97. (New) The composition of claim 31, wherein the inhibitor comprises boric acid.